TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

2 S C 4 9 1 5

HIGH FREQUENCY AMPLIFIER APPLICATIONS

FM, RF, MIX, IF AMPLIFIER APPLICATIONS

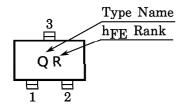
• Small Reverse Transfer Capacitance : $C_{re} = 0.55 pF$ (Typ.)

• Low Noise Figure: NF=2.3dB (Typ.)

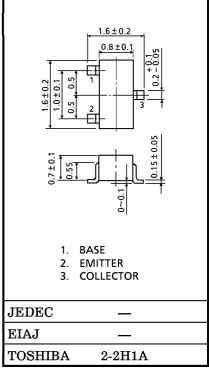
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	40	V
Collector-Emitter Voltage	v_{CEO}	30	V
Emitter-Base Voltage	$V_{ m EBO}$	4	V
Collector Current	$I_{\mathbf{C}}$	20	mA
Base Current	$I_{\mathbf{B}}$	4	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	100	mW
Junction Temperature	T_{j}	125	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	°C

Marking



Unit in mm



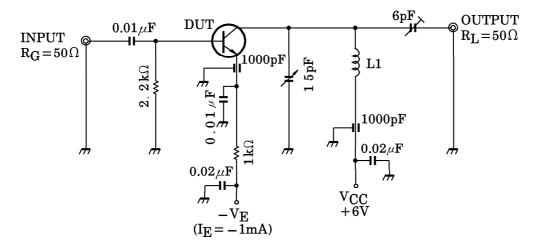
Weight: 2.4mg

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

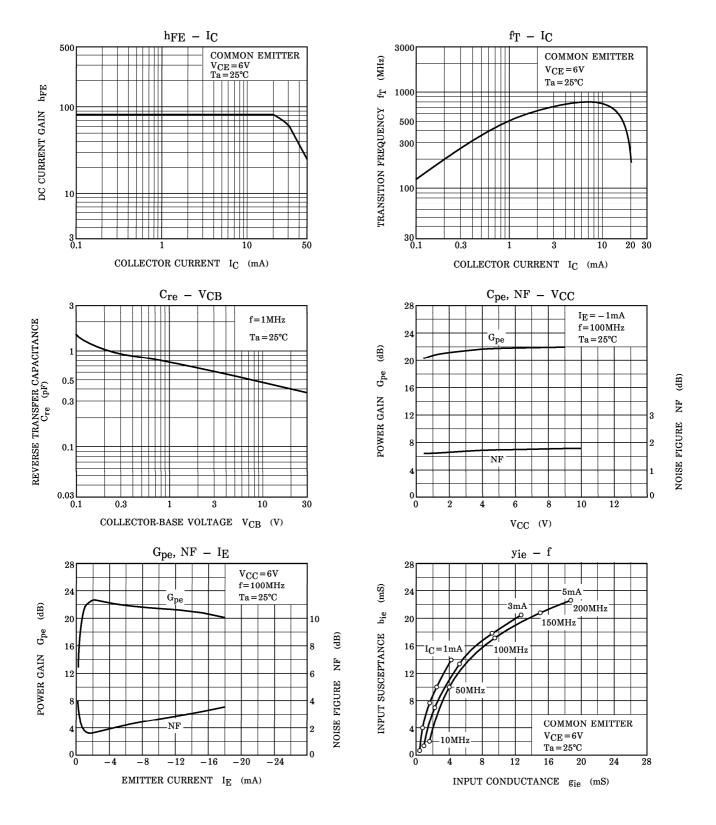
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 40V, I_{E} = 0A$	_	_	0.1	μ A
Emitter Cut-off Current	I_{EBO}	$V_{EB}=4V, I_{C}=0A$	_	_	0.5	μ A
DC Current Gain	h _{FE} (Note)	$V_{\rm CE}$ =6V, $I_{\rm C}$ =1mA	40	_	200	
Reverse Transfer	C	Van - 6V f - 1MHz		0.55		~F
Capacitance	$ m C_{re}$	$V_{CB} = 6V, f = 1MHz$	-	0.55	-	pF
Transition Frequency	$\mathbf{f_T}$	$V_{CE}=6V, I_{C}=1mA$	260	550	_	MHz
Collector-Base Time	C_{c} .rbb' $V_{CE} = 6V$, $I_{E} = -1mA$, $f = 30MHz$				20	na
Constant	C _c .rbb	VCE = 6V, $IE = -1mA$, $I = 50MHz$	_	_		ps
Noise Figure	NF	$V_{CC}=6V, I_E=-1mA,$	_	2.3	5.0	dB
Power Gain	$G_{ m pe}$	f=100MHz, Fig.1	17	23	_	dB

(Note) hFE Classification $R:40{\sim}80$, $O:70{\sim}140$, $Y:100{\sim}200$

Fig.1 NF, G_{pe} TEST CIRCUIT

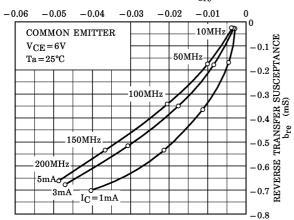


L1 : $0.8 \text{mm} \phi$ SILVER PLATED COPPER WIRE, 4T, 10mm ID, 8mm LENGTH



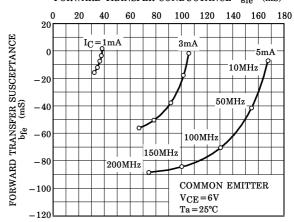
 $y_{re} - f$

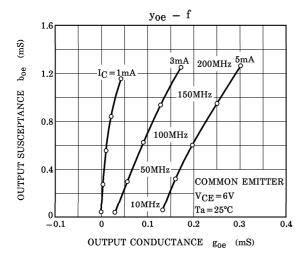
REVERSE TRANSFER CONDUCTANCE g_{re} (mS)

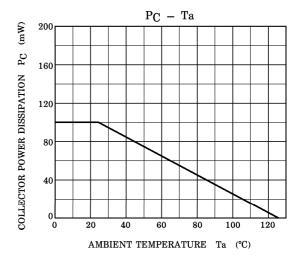


 $y_{fe} - f$

FORWARD TRANSFER CONDUCTANCE gfe (mS)







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